NPN Epitaxial Planar Silicon Transistor



2SC4920

Muting Circuit, Driver Applications

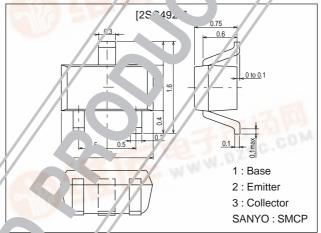
Features

- · High DC current gain.
- · On-chip bias resistance (R1=4.7k Ω , R2=4.7k Ω).
- · Very small-sized package permitting 2SC4920applied sets to be made smaller and slimmer.
- · Small ON resistance.

Package Dimensions

unit:mm

2106A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCPO		25	V
Collector-to-Emitter Voltage	VSED		20	V
Emitter-to-Base Voltage	V _E BO		10	V
Input Voltage	V _{IN}		18	V
Collector Current	I _C		100	mA
Collector Current (Pulse)	100		200	mA
Base Current	l'B		20	mA
Collector Dissipation	PC		150	mW
Junction Temperature	- I		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta 25 C

Parame (er	Symbol	Conditions	Ratings			Unit
Talalli le	Gymbol	Conditions	min	typ	max	Oilit
Collector Cutoff Current	ICEO	V _{CB} =20V, I _E =0		1	0.1	μΑ
	ICEO	V _{CE} =15V, I _B =0	40.7	-11	0.5	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0	410	532	760	μΑ
DC Current Gain	h _{FE}	V _{CE} =2V, I _C =20mA	80	77		
Gain-Bandwidth Product	f _T *	V _{CE} =5V, I _C =10mA		240		MHz
Output Capacitance	Cob*	V _{CB} =10V, f=1MHz		1.4		pF

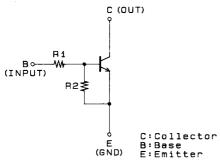
* Characteristic of the Stitu t transistor Marking . EA

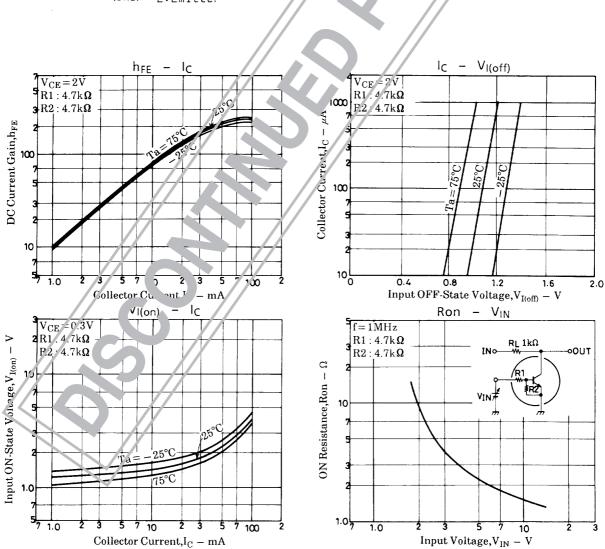
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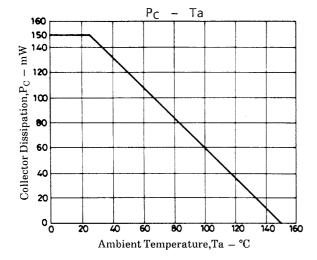
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters

Parameter	Symbol	Conditions	Ratings			Unit
		Conditions		typ	max	Offic
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =5mA, I _B =0.5mA		10	30	mV
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =10μA, I _E =0	25			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	20			V
Input OFF-State Voltage	V _{I(off)}	V _{CE} =2V, I _C =100μA	0.7	1.1	1.4	V
Input ON-State Voltage	V _{I(on)}	V _{CE} =0.3V, I _C =20mA	1.0	1.6	3.0	V
Input Resistance	R1		3.3	1.7	6.1	kΩ
Resistance Ratio	R1/R2		0.9	1.0	1.1	
ON Resistance	Ron	V _{IN} =5V, f=1MHz		2.2		Ω

Electrical Connection







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